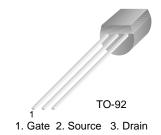


September 2007

2N5951 N-Channel RF Amplifier

- · This device is designed primarily for electronic switching applications such as low on resistance analog switching.
- Sourced from process 50.



Absolute Maximum Ratings* T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	30	V
V_{GS}	Gate-Source Voltage	-30	V
I_{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

^{*} This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES

1) These rating are based on a maximum junction temperature of 150 degrees C.

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

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²⁾ These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

$\textbf{Electrical Characteristics*} \ \, \textbf{T}_{a} = 25 ^{\circ} \textbf{C} \ \, \textbf{unless otherwise noted}$

Symbol	Parameter	lest Condition	win.	wax.	Units

Off Characteristics

$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$	-30		V
lana	Gate Reverse Current	$V_{GS} = 15V, V_{DS} = 0, T = 25^{\circ}C$		-1.0	nA
IGSS		T = 100°C		-200	шА
V _{GS(off)}	Gate-Source Cut-off Voltage	$V_{DS} = 15V, I_{D} = 100nA$	-2	-5	V
V_{GS}	Gate-Source Forward Voltage	$V_{DS} = 15V, I_D = 700\mu A$	-1.3	-4.5	V

On Characteristics

*I _{DSS}	Zero-Gate Voltage Drain Current *	$V_{DS} = 15V, V_{GS} = 0$	7	13	mA
Ros(on)	Drain-Source On Resistance	$I_D = 400 \mu A, f = 1.0 kHz$		250	Ω

Small Signal Characteristics

goss	Common- Source Output Conductance	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0kHz$	75	μ/Ω
gos	Output Conductance	$V_{DS} = 15V, V_{GS} = 0V, f = 100MHz$	100	μ/Ω
gis	Input Conductance	V _{DS} = 15V, V _{GS} = 0V, f = 100MHz	250	μ/Ω
Ciss	Input Capacitance	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz$	6	pF
Crss	Reverse Transfer Capacitance	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz$	2	pF
e n	Equivalent Short-Circuit Input Noise Voltage	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0kHz$	100	nV
NF	Noise Figure	$\begin{split} V_{DS} = 15 \text{V}, & V_{GS} = 0 \text{V}, \\ R_G = 1.0 \text{m}\Omega, & \text{f} = 1.0 \text{kHz} \\ R_G = 1.0 \text{k}\Omega, & \text{f} = 100 \text{MHz} \end{split}$	2 5	dB

^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle = 2%





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